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SEMITOP[®] 3

Antiparallel Thyristor Module

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Preliminary Data

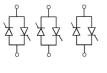
Features

- Compact Design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passived thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications

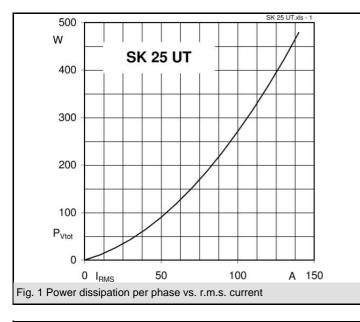
- Soft starters
- Light control (studios, theaters...)
- Temperature control

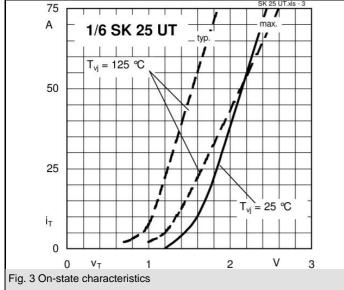
V _{RSM}	V _{RRM} , V _{DRM}		I _{RMS} = 29 A (full conduction)	
V V			(T _s = 85 °C)	
900 800		SK 25 UT 08		
1300 1200		SK 25 UT 12		
1700 1600		SK 25 UT 16		
1100	1000		3122 31 10	
Symbol	Conditions		Values	Units
I _{RMS}	1 1000 T 10000		20	А
TIMO			29	А
I _{TSM}	T _{vi} = 25 °C ; 10 ms		320	A
	T _{vi} = 125 °C ; 10 ms		280	А
i²t	T _{vi} = 25 °C ; 8,310 ms		510	A²s
	T _{vj} = 125 °C ; 8,310 ms		390	A²s
V _T	T _{vi} = 25 °C, I _T = 75 A		max. 2,45	V
V _{T(TO)}	T _{vi} = 125 °C		max. 1,1	V
r _T	T _{vi} = 125 °C		max. 20	mΩ
I _{DD} ;I _{RD}	$T_{vj} = 125 \text{ °C}, V_{RD} = V_{RRM}$		max. 8	mA
t _{gd}	$ T_{vj} = 125 \text{ °C}, V_{RD} = V_{RRM} $ $ T_{vj} = 25 \text{ °C}, I_G = 1 \text{ A}; di_G/dt = 1 \text{ A/}\mu\text{s} $		1	μs
t _{gr}	$V_{\rm D} = 0.67 \ {}^{*}V_{\rm DRM}$		1	μs
(dv/dt) _{cr}	T _{vi} = 125 °C		1000	V/µs
(di/dt) _{cr}	T _{vi} = 125 °C; f= 5060 Hz		50	A/µs
t _q	T _{vj} = 125 °C; typ.		80	μs
I _H	T _{vj} = 25 °C; typ. / max.		80 / 150	mA
۱ _L	T_{vj} = 25 °C; R_G = 33 Ω ; typ. / max.		150 / 300	mA
V _{GT}	T _{vj} = 25 °C; d.c.		min. 2	V
I _{GT}	$T_{vj} = 25 \ ^{\circ}C; \ d.c.$		min. 100	mA
V_{GD}	T _{vj} = 125 °C; d.c.		max. 0,25	V
I _{GD}	T _{vj} = 125 °C; d.c.		max. 3	mA
R _{th(j-s)}	cont. per thyristor		1,7	K/W
	sin 180° per thyristor		1,78	K/W
R _{th(j-s)}	cont. per W1C		0,85	K/W
	sin 180° per W1C		0,89	K/W
T _{vj}			-40 +125	°C
T _{stg}			-40 +125	°C
T _{solder}	terminals, 10s		260	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1	min.	3000 / 2500	V~
M _s	Mounting torque to heatsink		2,5	Nm
Mt				Nm
а				m/s²
m			30	g
Case	SEMITOP [®] 3		T 13	

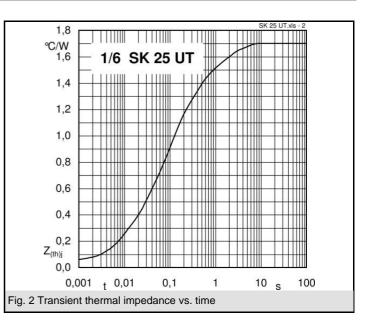


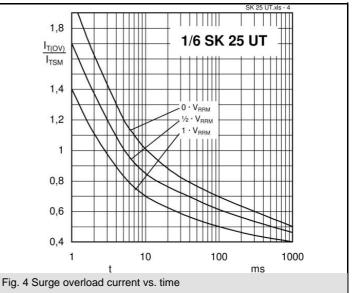
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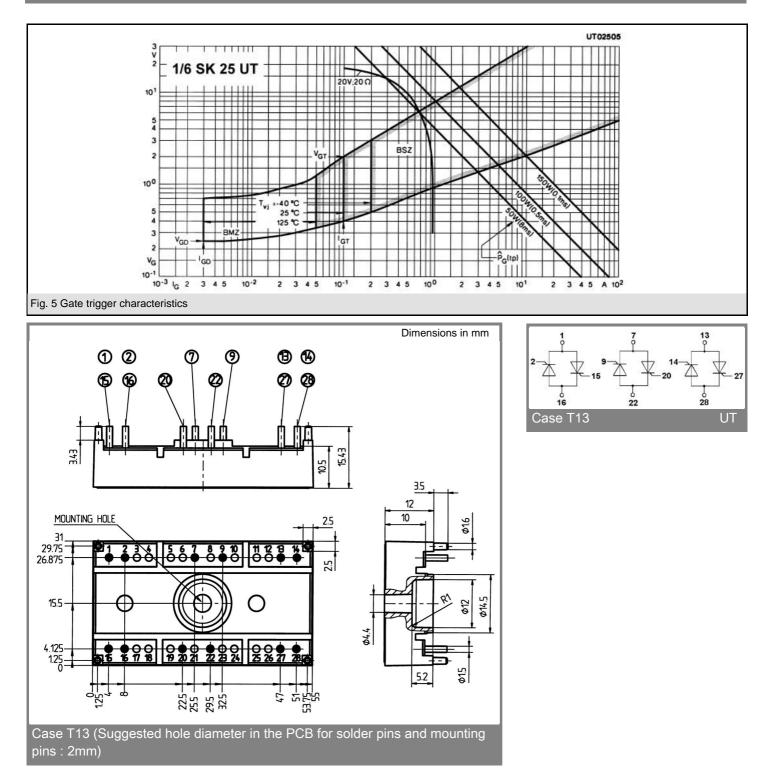








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